COMPLIANT

HALOGEN

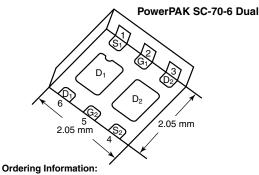
FREE





Dual P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY								
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)					
- 20	$0.059 \text{ at V}_{GS} = -4.5 \text{ V}$	- 4.5 ^a	4.9 nC					
	0.098 at V _{GS} = - 2.5 V	- 4.5 ^a	4.9110					



SiA921EDJ-T1-GE3 (Lead (Pb)-free and Halogen-free) SiA921EDJ-T4-GE3 (Lead (Pb)-free and Halogen-free)

Marking Code Part # code ot Traceability and Date code

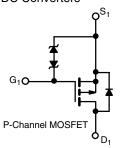
FEATURES

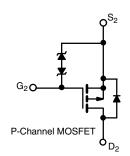
- TrenchFET® Power MOSFET
- Thermally Enhanced PowerPAK® SC-70 Package
 - Small Footprint Area
 - Low On-Resistance
- Typical ESD Protection: 1700 V
- High Speed Switching
- Material categorization:

For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Load Switch, PA Switch and Battery Switch for Portable **Devices**
- DC/DC Converters





ABSOLUTE MAXIMUM RATINGS	$T_A = 25 ^{\circ}C$, unle	ess otherwise no	ted)			
Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	- 20	V		
Gate-Source Voltage		V _{GS}	± 12	□		
Continuous Drain Current (T _J = 150 °C)	$T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 70 ^{\circ}\text{C}$ $T_{A} = 25 ^{\circ}\text{C}$ $T_{A} = 70 ^{\circ}\text{C}$	I _D	- 4.5 ^a - 4.5 ^a - 4.5 ^a - 4.5 ^a , b, c - 3.7 ^b , c	A		
Pulsed Drain Current	•	I _{DM}	- 15	7		
Continuous Source-Drain Diode Current	$T_C = 25 ^{\circ}C$ $T_A = 25 ^{\circ}C$	I _S	- 4.5 ^a - 1.6 ^{b, c}	\exists		
Maximum Power Dissipation	$T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 70 ^{\circ}\text{C}$ $T_{A} = 25 ^{\circ}\text{C}$ $T_{A} = 70 ^{\circ}\text{C}$	P _D	7.8 5 1.9 ^{b, c} 1.2 ^{b, c}	w		
Operating Junction and Storage Temperature Ra	ange	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature	e) ^{d, e}		260			

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient ^{b, f}	t ≤ 5 s	R _{thJA}	52	65	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	12.5	16	O/ VV				

Notes:

- a. Package limited.
- b. Surface mounted on 1" x 1" FR4 board.
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under steady state conditions is 110 °C/W.

Document Number: 64734 S12-2731-Rev. C, 12-Nov-12 For technical questions, contact:: pmostechsupport@vishay.com



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)									
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit			
Static	l v	V 0VI 050			<u> </u>				
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V			
V _{DS} Temperature Coefficient	ΔV _{DS} /T _J	I _D = - 250 μA		- 14		mV/°C			
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			2.5					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.5		- 1.4	V			
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1	_			
	400	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 10	μΑ			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1	μΛ			
	D00	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			- 10				
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le$ - 5 V, $V_{GS} =$ - 4.5 V	- 15			Α			
Dunin Course On Chata Desistance	Book	$V_{GS} = -4.5 \text{ V}, I_D = -3.6 \text{ A}$		0.048	0.059	0			
Drain-Source On-State Resistance ^a	H _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 1.5 A		0.080	0.098	Ω			
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 3.6 A		11		S			
Dynamic ^b									
		$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -4.7 \text{ A}$		15	23	nC			
Total Gate Charge	Q_g			7.1	11				
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -4.7 \text{ A}$		1.3					
Gate-Drain Charge	Q_{gd}			2.1					
Gate Resistance	R_{g}	f = 1 MHz		6.3		Ω			
Turn-On Delay Time	t _{d(on)}			20	30	-			
Rise Time	t _r	$V_{DD} = -10 \text{ V, R}_{L} = 2.7 \Omega$		20	30				
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 3.7 A, V_{GEN} = - 4.5 V, R_g = 1 Ω		25	40				
Fall Time	t _f			10	15				
Turn-On Delay Time	t _{d(on)}			5	10	ns			
Rise Time	t _r	$V_{DD} = -10 \text{ V, R}_{1} = 2.7 \Omega$		12	20				
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -3.7 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		25	40	_			
Fall Time	t _f			10	15				
Drain-Source Body Diode Characterist				<u> </u>		1			
Continuous Source-Drain Diode Current	Is	T _C = 25 °C			- 4.5				
Pulse Diode Forward Current	I _{SM}				- 15	A			
Body Diode Voltage	V _{SD}	I _S = - 3.7 A, V _{GS} = 0 V		- 0.9	- 1.2	V			
Body Diode Reverse Recovery Time	t _{rr}			15	30	ns			
Body Diode Reverse Recovery Charge	Q _{rr}	0.7.4 41/41 400.4/ 7 07.00		6	12	nC			
Reverse Recovery Fall Time	t _a	$I_F = -3.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		8.5		ns			
Reverse Recovery Rise Time	t _b			6.5					
·		<u> </u>			1	1			

Notes:

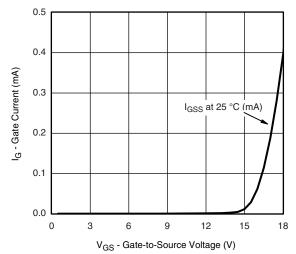
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

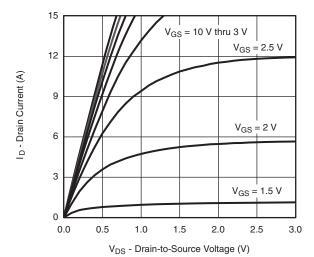
b. Guaranteed by design, not subject to production testing.



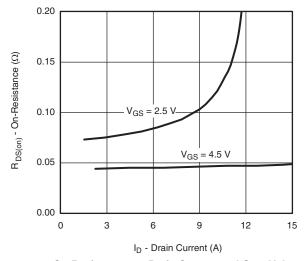
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



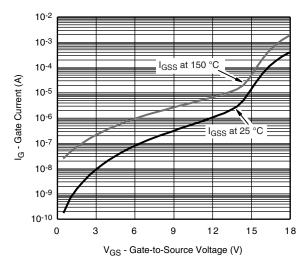
Gate Current vs. Gate-to-Source Voltage



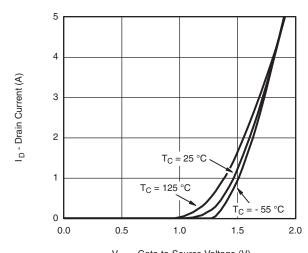
Output Characteristics



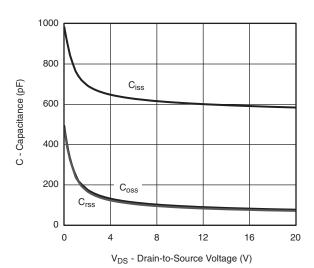
On-Resistance vs. Drain Current and Gate Voltage



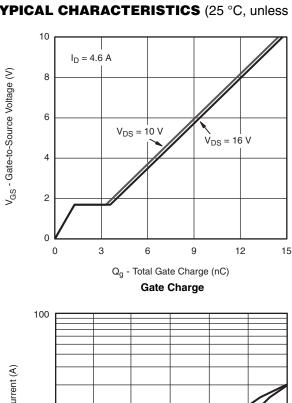
Gate Current vs. Gate-to-Source Voltage

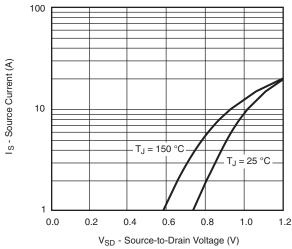


V_{GS} - Gate-to-Source Voltage (V) **Transfer Characteristics**

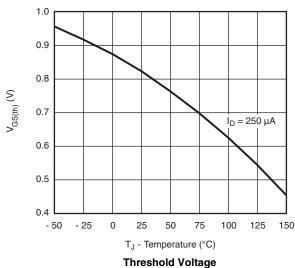


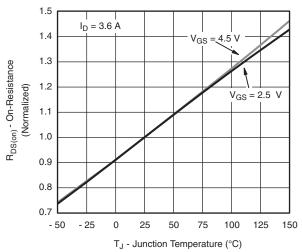
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



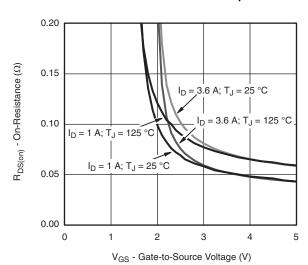




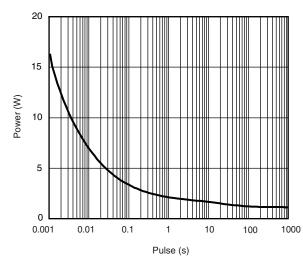




On-Resistance vs. Junction Temperature



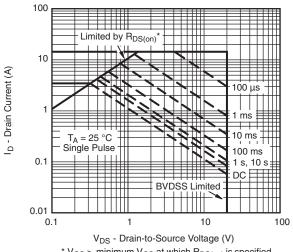
On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



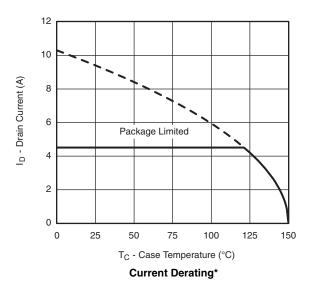
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

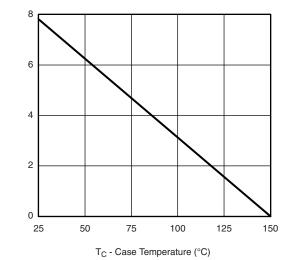


* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Ambient

Power Dissipation (W)



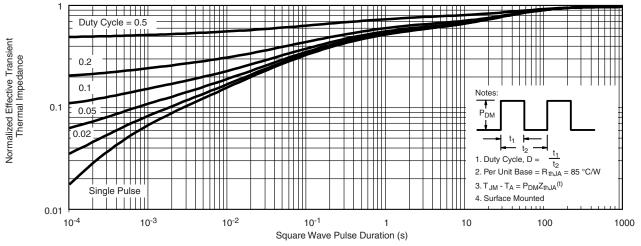


Power Derating

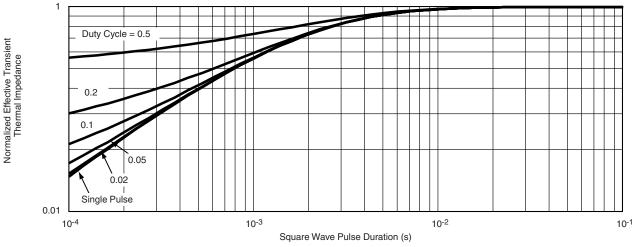
 $^{^{\}star}$ The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



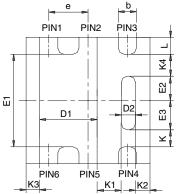
Normalized Thermal Transient Impedance, Junction-to-Case

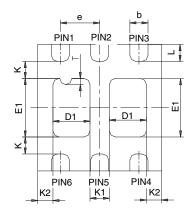
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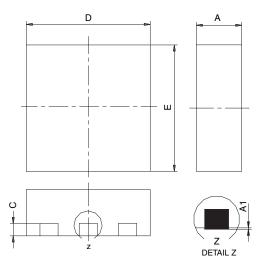
PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
 Package outline exclusive of mold flash and metal burr
 Package outline inclusive of plating

			SINGL	E PAD			DUAL PAD					
DIM	M	ILLIMETER	RS		INCHES		М	MILLIMETERS		INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A 1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC			0.026 BSC	;	0.65 BSC			0.026 BSC		
K		0.275 TYP			0.011 TYP		0.275 TYP		0.011 TYP			
K1		0.400 TYP			0.016 TYP		0.320 TYP		0.013 TYP			
K2		0.240 TYP		0.009 TYP		0.252 TYP		0.010 TYP				
К3		0.225 TYP		0.009 TYP								
K4		0.355 TYP		0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
Т							0.05	0.10	0.15	0.002	0.004	0.006
ECNI: C O	N: C 07/21 Poy C 06 Aug 07											

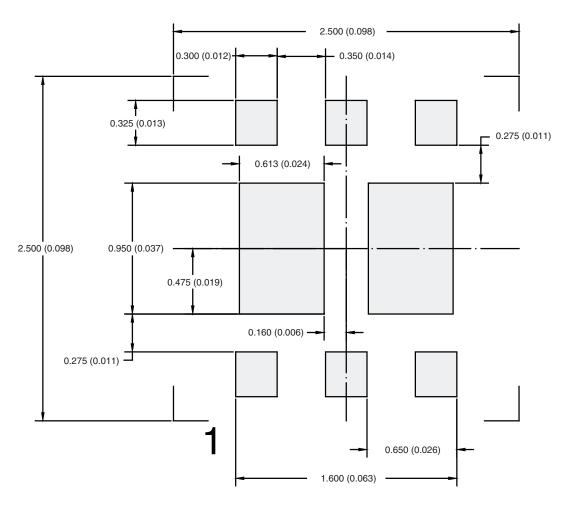
ECN: C-07431 - Rev. C, 06-Aug-07

DWG: 5934

Document Number: 73001 06-Aug-07

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RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Dual



Dimensions in mm (inches)

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